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1 First-principles DFT Insights into the Stabilization of Zinc Diphosphide (ZnP<sub>2</sub>) Nanocrystals

2 via Surface Functionalisation by 4-Aminothiophenol for Photovoltaic Applications

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## 14 ABSTRACT

The resurgence of interest in zinc phosphide compounds as efficient solar absorbers has initiated 15 16 increasing efforts to improve their stability under humid and oxygen-rich conditions. Although organic functionalisation has been suggested as a promising strategy to passivate zinc phosphide 17 18 nanoparticles, fundamental atomic-level insights into the adsorption processes and structures at zinc diphosphide (ZnP<sub>2</sub>) surfaces is still lacking. In this study, the interactions between 4-aminothiophenol 19 and the low Miller index surfaces of monoclinic ZnP<sub>2</sub> have been investigated by means of density 20 functional theory (DFT) calculations. A bidentate adsorption mode, in which the 4-aminothiophenol 21 binds through both its functional groups via Zn-N and Zn-S bonds, was predicted to be the strongest 22 form of interaction and monolayer-functionalised ZnP<sub>2</sub> surfaces were found to be highly stable under 23 adsorbate-rich conditions. Changes in the equilibrium morphology of ZnP<sub>2</sub> nanocrystallites upon 24 functionalisation and effects of humidity are also discussed. The results are expected to contribute 25 towards the rational design of ZnP<sub>2</sub>-based materials for photovoltaic devices. 26

27 **KEYWORDS:** zinc diphosphide, 4-aminothiophenol, DFT, functionalisation, photovoltaics.

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#### 30 GRAPHICAL ABSTRACT



# 31

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#### 33 1 INTRODUCTION

Earth-abundant semiconducting materials are attractive solutions in large-scale energy conversion 34 and storage deployment <sup>1,2</sup>. There is resurgence of interest in Zn-P compounds as promising materials 35 for cost-effective and scalable thin-film PV applications <sup>3–6</sup>, because their constituent elements are 36 non-toxic, widely available, and more affordable alternatives to currently employed PV materials<sup>7</sup>. 37 Among various Zn-P compounds, the tetragonal  $Zn_3P_2$  has received particular attention owing to its 38 suitable direct band gap of 1.5 eV<sup>8</sup>, high visible-light absorption and extinction coefficient (>10<sup>4</sup> 39  $cm^{-1}$ )<sup>9,10</sup>, and long minority-carrier diffusion length (~10 µm)<sup>11</sup>. Although the band gap energies of 40 the monoclinic  $ZnP_2$  member, reported in the range of 1.33-1.60 eV  $^{12-14}$ , also fall within the values 41 of the maximum absorption efficiency described by the Shockley-Queisser limit <sup>15–17</sup>, it has been 42 largely overlooked as a candidate for PV applications. It has, however, been investigated and used as 43 anode material in Li-ion and Na-ion batteries, together with its tetragonal polymorph and  $Zn_3P_2$ 44 counterparts  $^{18-20}$ , where ZnP<sub>2</sub> has shown to outperform Zn<sub>3</sub>P<sub>2</sub> in electrochemical performance for it 45 has higher reversible capacity. In a recent DFT study, we have systematically characterised the 46 mechanical, structural, and electronic properties of both tetragonal and monoclinic ZnP2 and 47 discussed their implications for PV applications<sup>21</sup>. The spectroscopic limited maximum efficiency 48

49 (SLME) of monoclinic ZnP<sub>2</sub> was computed to be 10% for a reasonable reference thickness of 0.5 μm,
50 demonstrating its promising potential as a photovoltaic material.

However, an inherent drawback of zinc-based semiconducting materials is their low surface stability 51 in the presence of moisture and oxygen <sup>22-26</sup>, and efforts are now directed towards surface 52 modification to aid their integration into photovoltaic devices and exploit their suitable optoelectronic 53 properties. An important part of these investigations has focused on the modification of known 54 inorganic semiconductor surfaces with organic molecules. Organic functionalisation can enhance the 55 surface stability against temperature and possible oxidation in the presence of oxygen and moisture 56 that could result in material degradation. Protection strategies of zinc-based semiconductors (e.g. Zn-57  $O^{27-29}$ , Zn-S  $^{30-32}$ , Zn<sub>3</sub>P<sub>2</sub>  $^{8,33}$ , Zn<sub>3</sub>N<sub>2</sub>  $^{34,35}$ , ZnSe  $^{36,37}$ ) for photovoltaic applications, employing different 58 surfactant molecules ranging from amines <sup>38</sup>, over acids <sup>39</sup> and thiols <sup>40</sup>, to polymers <sup>41–43</sup>, have been 59 developed and successfully applied in the laboratory. In addition, hybrid organic-inorganic 60 nanostructures are of great interest because their optical and electrical properties can be efficiently 61 tailored by surface functionalisation. For example, surface modification of ZnO nanoparticles with 62 pyrene-1-carboxylic acid showed an increase in the short circuit current densities with lower open 63 circuit voltage, which was assigned to better carrier collection <sup>39</sup>. Furthermore, large scale 64 functionalisation of Zn<sub>3</sub>P<sub>2</sub> nanowires was achieved experimentally with two different ligand 65 molecules, 4-aminothiophenol and 3-propanedithiol. Both systems were found to be stable over 120 66 days without any agglomeration or degradation, thus providing a promising method for  $Zn_3P_2$ 67 passivation <sup>40</sup>. Based on these results, theoretical insight was reported on the adsorption strength and 68 charge transfer between the 4-aminothiophenol and 3-propanedithiol and the Zn<sub>3</sub>P<sub>2</sub> nanowires, which 69 were represented by a (100) slab  $^{44}$ . A more recent study focused on the functionalisation of  $Zn_3P_2$ 70 71 nanocrystals with 4-aminothiophenol and its influence on the electronic properties of varying surfaces of the material <sup>45</sup>. Different coupling schemes of available functional groups have been investigated 72 and inequivalent interacting modes were assigned as the most favourable for distinct Zn<sub>3</sub>P<sub>2</sub> surfaces. 73

Despite extensive investigations on the functionalisation of Zn<sub>3</sub>P<sub>2</sub>, no studies have been dedicated to 74 the characterisation of the interface chemistry between ZnP<sub>2</sub> and organic molecules, which makes 75 this work timely. In the present study, a series of comprehensive DFT calculations were carried out, 76 77 aimed at unravelling the mechanism of adsorption of 4-aminothiophenol on the low Miller index surfaces of monoclinic ZnP<sub>2</sub> and depict the properties of the resulting hybrid structures. Atomic-level 78 79 calculations based on DFT techniques have become powerful tools to describe organic-inorganic interfaces because they are capable of accurately predicting the lowest-energy adsorption geometries 80 and identifying the charge transfer and other electronic effects <sup>46,47</sup>. As the 4-aminothiophenol has 81 two functional groups (thiol (-SH) and amine (-NH<sub>2</sub>) end group), different binding modes that 82 involve one or both functional groups and structures have been considered and the energetics of the 83 obtained adsorption configurations have been analysed. Using predicted surface energies, the 84 equilibrium morphologies of ZnP<sub>2</sub> nanocrystals before and after functionalisation with 4-85 aminothiophenol were constructed according to the Wulff theorem. The results are expected to 86 provide useful information about the interactions between ZnP<sub>2</sub> and organic molecules for future 87 functionalisation strategies and shape modulation of ZnP<sub>2</sub> nanoparticles. 88

89 2

#### **2** COMPUTATION DETAILS

The spin-polarised Kohn-Sham density functional theory (KS-DFT) <sup>48,49</sup> calculations were carried 90 out within the Vienna Ab-initio Simulation Package (VASP) <sup>50</sup>. The exchange-correlation functional 91 was approximated using the Perdew-Burke-Ernzerhof (PBE) parametrisation of the generalized 92 gradient approximation (GGA) for structural relaxations, whereas the hybrid HSE06 functional was 93 employed for the calculation of electronic properties.<sup>51</sup> The projector augmented wave (PAW) <sup>52,53</sup> 94 pseudo-potential method was imposed and core electrons up to and including the 3p for Zn, 2p for P 95 and S, and 1s levels for N and O, respectively, were kept frozen. The long-range dispersion 96 interactions were added through the DFT-D3 method, as developed by Grimme et al 54. 97

The kinetic energy cut-off of the wave functions was set to 500 eV, with bulk calculations carried out in the reciprocal space with a  $5 \times 5 \times 5$  k-point mesh. The METADISE code <sup>55</sup> was employed to

construct the surfaces and final surface models were built as slabs of material with periodic boundary 100 conditions and a 20 Å vacuum was added in the direction orthogonal to the surface to prevent 101 interaction between vertical images. Each surface slab is built of twelve atomic layers, comprising 102 103 four ZnP-P-ZnP trilayers that each contain four ZnP<sub>2</sub> units, schematically represented for the (001) surface in Figure S1 of supplementary information, SI. All atoms in the surface slab were allowed to 104 relax and a k-point mesh of  $5 \times 5 \times 1$  was used for the surface relaxations. The conjugate gradient 105 technique, with total energy and force convergence criteria set at  $10^{-6}$  eV and 0.01 eV/Å, respectively, 106 107 has been used to perform structural optimisations.

108 Surface energies of relaxed bare slabs ( $\gamma$ ) have been calculated as:

109 
$$\gamma = \frac{E_{\text{slab}}^{\text{DFT}} - n \times E_{\text{bulk}}^{\text{DFT}}}{2A_{\text{slab}}},$$
 (1)

110 where  $E_{\text{slab}}^{\text{DFT}}$  and  $E_{\text{bulk}}^{\text{DFT}}$  represent the DFT energies of relaxed slab and bulk, respectively,  $A_{\text{slab}}$  is the 111 surface area, and *n* is the ratio between the number of atoms in the slab and the number of atoms in 112 the bulk. The electronic work function ( $\phi$ ), i.e. the energy required to withdraw an electron from the 113 solid to the vacuum, was calculated as the difference of the vacuum electrostatic potential energy and 114 the Fermi energy.

Adsorption of 4-aminothiophenol was carried out on the  $2 \times 1$  ((011), (101), and (111)) and  $2 \times 2$ 115 ((001), (010), (100), and (110)) supercells of the ZnP<sub>2</sub> surfaces to minimise the lateral interactions 116 between the adsorbate molecules. The k-point mesh was subsequently reduced to a Gamma point 117 only as the cell vectors reached lengths over 30 Å. Three initial adsorption modes were chosen, a 118 single horizontal and two vertical geometries, one with the -SH and the other with the -NH<sub>2</sub> group 119 facing the surface. No constrains on surface atoms or the adsorbing molecule were imposed during 120 the optimisation. In particular, the 4-aminothiophenol molecule was free to move laterally and 121 122 vertically from its initial binding site or reorient itself to find the lowest-energy adsorption geometry. 123 The strength of interaction between 4-aminothiophenol and  $ZnP_2$  surfaces was characterized by the 124 adsorption energy ( $E_{ads}$ ), calculated as:

125 
$$E_{ads} = E_{surface+adsorbate}^{DFT} - (E_{surface}^{DFT} + E_{adsorbate}^{DFT})$$
(2)

with  $E_{\text{surface+adsorbate}}^{\text{DFT}}$ ,  $E_{\text{surface}}^{\text{DFT}}$ , and  $E_{\text{adsorbate}}^{\text{DFT}}$  representing calculated energies of the surface with adsorbed 4-aminothiophenol, bare surface, and a 4-aminothiophenol molecule in a box, respectively. Negative  $E_{\text{ads}}$  indicates spontaneous adsorption of the molecule onto the surface with the most stable adsorption mode characterised by the most negative adsorption energy. The reference energy of a single adsorbate molecule was determined by optimising it in a cubic box of 15 Å a side and sampling only over a Gamma point.

Full coverage functionalisation was carried out only for the most favourable adsorption mode, where the surface is considered to be fully functionalised once all the zinc atoms on the surface are unavailable for further adsorption. Surface energies after functionalisation ( $\gamma_f$ ) were determined as:

135 
$$\gamma_f = \frac{E_{\text{func surface}}^{\text{DFT}} - (n \times E_{\text{bulk}}^{\text{DFT}} + m \times E_{\text{adsorbate}}^{\text{DFT}})}{2A_{\text{slab}}}$$
(3)

136 where  $E_{\text{func surface}}^{\text{DFT}}$  is the calculated energy of the surface functionalised by a full monolayer, and *m* is 137 the number of adsorbed 4-aminothiophenol molecules. Calculated surface energies were 138 subsequently employed to obtain Wulff morphologies <sup>56</sup>, as implemented in the Wulffmaker <sup>57</sup> 139 software.

#### 140 3 RESULTS AND DISCUSSION

# 141 **3.1 Bulk and surface characterisation of ZnP**<sub>2</sub>

The monoclinic ZnP<sub>2</sub> bulk structure (Figure 1a), optimised at the GGA level, has lattice parameters of a=8.611 Å, b=7.239 Å, and c=7.530 Å, which agree well with the available experimental data <sup>12</sup> of a=8.863 Å, b=7.288 Å, c=7.560 Å. In our previous study <sup>21</sup>, we found that standard GGA significantly underestimated the electronic band gap of monoclinic ZnP<sub>2</sub>, with the calculated value
of 0.76 eV being only half the experimental band gap, reported in the range of 1.33-1.60 eV <sup>13,58-60</sup>.
To resolve this deficiency, the hybrid HSE06 functional was employed, yielding an electronic band
gap of 1.46 eV, in good agreement with experimental data. The orbital-decomposed densities of state
computed with the GGA (PBE) and HSE06 functional are shown in Figure 1b and c, respectively.



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**Figure 1:** Optimised structure of bulk monoclinic  $ZnP_2$  (a) and its orbital decomoposed densities of state computed with the GGA (PBE) (b) and HSE06 (c) functionals.

From the optimised bulk structure, the seven low Miller index surfaces were cut and relaxed by GGA 153 in order to determine their optimal arrangements and stabilities. Shown in Figure 2 are the optimised 154 structures of the most stable terminations of the seven surfaces, with the calculated unrelaxed and 155 156 relaxed surface energies reported in Table 1. According to the calculated percentage relaxations, all surfaces undergo significant adjustments to reach the most stable configuration. The relaxed surfaces 157 exhibit similar stabilities, as reflected in the small differences in their final surface energies. The (001) 158 and (011) surfaces are predicted as the most stable with surface energies of 0.728 and 0.739 Jm<sup>-2</sup>, 159 respectively. They are followed by the (100) and (101) surfaces whose calculated surface energies 160 are 0.889 and 0.899 Jm<sup>-2</sup>, respectively. With surface energies of 0.949, 1.028 and 0.985 Jm<sup>-2</sup>, the 161 (010), (110) and (111) surfaces are predicted to be less favourable, suggesting that the (110) surface 162 is the least stable low Miller index surface of monoclinic ZnP<sub>2</sub>. Considering that all surfaces have 163 164 similar stabilities and are hence likely to be expressed in the nanocrystal structure of  $ZnP_2$ , the adsorption of 4-aminotiophenol (Figure 2, leftmost) was investigated on each surface to compare the 165 nanocrystal morphologies before and after functionalisation. 166



168 *Figure 2:* Optimised structures of 4-aminothiophenol (leftmost) and seven low Miller index surfaces of 169 monoclinic  $ZnP_2$  in top and side views. To create a depth perception, the top-most surface atoms have been 170 represented with more vivid colors.

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167

Table 1 Calculated surface energies (unrelaxed ( $\gamma_u$ ) and relaxed ( $\gamma_r$ )), percentage relaxation, and work functions ( $\phi$ ) of most stable terminations of the seven low Miller index ZnP<sub>2</sub> surfaces.

surface	termination	$\gamma_{\rm u}$ / Jm <sup>-2</sup>	$\gamma_r$ / Jm <sup>-2</sup>	relaxation / %	$\phi$ / eV
(001)	-Zn-Zn-	1.006	0.728	-27.63	4.614
(010)	-P-P-	1.278	0.949	-25.74	4.561
(011)	-Zn-	1.001	0.739	-26.17	4.245
(100)	-P-Zn-	1.514	0.889	-41.28	4.429
(101)	-P-P-	1.165	0.899	-22.83	4.382
(110)	-P-	1.699	1.028	-39.49	4.402
(111)	-Zn-	1.364	0.985	-27.79	4.139

<sup>174</sup> 

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# 3.1 Single 4-aminothiophenol adsorption on ZnP<sub>2</sub> surfaces

To determine the preferred binding modes of the 4-aminothiophenol molecule on the various low Miller index surfaces of  $ZnP_2$ , several different initial adsorption orientations were optimised without any symmetry constraints.

ZnP<sub>2</sub> (001) surface: At the ZnP<sub>2</sub> (001) surface, the 4-aminothiophenol binds in three possible modes 179 180 as shown in Figure 3. The calculated adsorption energies, interatomic bond distances, and charge transfer are summarised in Table 2. The most stable binding mode is predicted to be a bidentate 181 geometry (Figure 3a), wherein the 4-aminothiophenol molecule adsorbed parallel to the surface 182 forming both N-Zn (2.26 Å) and S-Zn (2.64 Å) bond. This structure released an adsorption energy of 183 -1.27 eV. Two vertical monodentate configurations, one binding through the sulphur of the thiol 184 group (Figure 3b) and the other through the nitrogen of the amino group (Figure 3c), relaxed to 185 differently slanted structures. Binding of 4-aminothiophenol through the thiol group resulted in 186 repositioning horizontally towards the surface, with an angle between the N-S vector and a plane of 187

the surface (Figure S2 of SI) of 7.30° and a shorter S-Zn bond of 2.57 Å compared to the same bond of the bidentate interaction mode. When interacting solely through the -NH<sub>2</sub> group, the 4aminothiophenol molecule remains vertically oriented with an angle of 73.89° and a N-Zn distance of 2.17 Å, which is also shorter than when adsorbed as a bidentate. However, the adsorption energies of both monodentate modes show weaker interaction and are calculated to be  $E_{ads} = -1.15$  and  $E_{ads} =$ -1.07 eV for -SH and -NH<sub>2</sub> interacting groups, respectively.



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Regardless of the interaction mode of the adsorption, a molecule of 4-aminothiophenol gained electronic charge upon binding to the  $ZnP_2$  (001) surface. The amount of charge gained though a single Zn-N bond in the -NH<sub>s</sub> vertical binding mode, namely -0.06 e<sup>-</sup>, is only half of what is transferred in the horizontal or -SH vertical mode (-0.14 and -0.13 e<sup>-</sup>, respectively). However, the zinc atom directly involved in the adsorption of the molecule through the -NH<sub>s</sub> group loses more than double the charge contained within the adsorbate. The remaining negative charge is traced to the topmost neighbouring phosphorus atom (-0.06 e<sup>-</sup>) connected to the interacting zinc. All structural and

- 207 electronic parameters are listed in Table 2, while distribution of gained charge over atoms of the 4-
- aminothiophenol molecule can be found in Table S1, SI.

**Table 2:** Adsorption energies  $(E_{ads})$ , bond lengths (d), angles between the N-S vector and a surface plane  $(\theta)$ , and changes in the Bader charge  $(\Delta q)$  upon the adsorption of a single 4-aminothiophenol molecule on low Miller index surfaces of monoclinic ZnP<sub>2</sub>. Structural parameters are obtained through the relaxation with GGA (PBE) exchange functional, while HSE06 was used to calculate Bader charges. Negative changes in

213 Bader charge represent gain in the electronic charge, while positive changes represent loss of electrons.

curfaco	hinding mode	E <sub>ads</sub> /	d (S-Zn) /	d (N-Zn)	<b>∩</b> / °	$\Delta q$ (adsorbate)	Δq (Zn <sub>s</sub> )	∆q (Zn <sub>N</sub> )
surface	binding mode	eV	Å	/ Å	07	/ e⁻	/ e⁻	/ e⁻
(001)	horizontal	-1.27	2.64	2.26		-0.14	0.02	0.06
	-SH vertical	-1.15	2.57		7.30	-0.13	0.01	
	-NH <sub>2</sub> vertical	-1.07		2.17	73.89	-0.06		0.10
(010)	horizontal	-2.04	2.70	2.26		-0.06	0.01	0.08
	-SH vertical	-1.47	2.52		74.75	-0.07	0.02	
	-NH <sub>2</sub> vertical	-0.98	2.18		69.82	-0.09		0.11
(011)	horizontal	-1.65	2.83	2.31		-0.09	0.02	0.06
	-SH vertical	-1.08	2.47		88.19	-0.11	0.03	
	-NH <sub>2</sub> vertical	-0.92		2.18	28.30	-0.08		0.09
(100)	horizontal	-1.47	2.56	2.36		-0.11	0.00	0.04
	-SH vertical	-1.33	2.50		10.00	-0.12	0.02	
	-NH <sub>2</sub> vertical	-0.78		2.19	80.05	-0.08		0.09
(101)	horizontal	-1.91	2.54	2.17		-0.16	0.03	0.09
	-SH vertical	-0.79	2.53		86.90	-0.08	0.03	
	-NH <sub>2</sub> vertical	-1.17		2.17	70.51	-0.08		0.07
(110)	horizontal	-1.38	2.45	(4.31)		-0.06	0.02	
(111)	horizontal	-1.41	2.52	(3.89)		-0.13	0.06	0.01
	-SH vertical	-0.82	2.58		32.72	-0.11	0.07	
	-NH <sub>2</sub> vertical	-1.23	2.15	2.15	60.48	-0.09		0.13

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ZnP<sub>2</sub> (010) surface: The optimised binding modes of 4-aminothiophenol on the ZnP<sub>2</sub> (010) surface 215 are presented in Figure 4. The channel-like structure of this surface, as indicated in Figure 2, can 216 accommodate the 4-aminothiophenol molecule horizontally inside the channel, allowing for a 217 relatively strong bidentate interaction (Figure 4a) with adsorption energy of  $E_{ads} = -2.04$  eV. 218 Established S-Zn and N-Zn bonds have lengths of 2.70 and 2.26 Å, respectively, and the whole 219 molecule gained a charge of -0.056 e<sup>-</sup>, mostly from the zinc atom interacting with the -NH<sub>2</sub> functional 220 group. When adsorbed vertically through the -SH functional group (Figure 4b), sulphur binds to the 221 Zn atom situated inside the surface channel (2.52 Å Zn-S bond), releasing an adsorption energy of -222 1.47 eV, with -0.068 e<sup>-</sup> of charge transferred to the adsorbate. When adsorbed via the amine nitrogen 223 in a vertical monodentate geometry (Figure 4c), the bulkiness of the -NH<sub>2</sub> functional group prevents 224 adsorption directly inside the channel and the N atom binds to an outer zinc atom instead (2.18 Å Zn-225

N bond). Without further interactions between the rest of the molecule and the  $ZnP_2$  (010) surface, the -NH<sub>2</sub> vertical binding mode released an adsorption energy of -0.98 eV, which is only half as favourable as the bidentate interaction. However, in this mode 4-aminothiophenol acquires the highest amount of charge from the surface, -0.086 e<sup>-</sup>.



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Figure 4 Top (top panel) and side views (bottom panle) of horizontal (a), -SH vertical (b), and -NH<sub>2</sub> vertical (c) adsorption modes of 4-aminothiophenol on the  $ZnP_2$  (010). For clarity, only the top most layers of the surface are shown. Calculated adsorption energies are listed below each structure. For colour legend refer to Figure 2.

ZnP<sub>2</sub> (011) surface: The optimised structures of the three binding modes of 4-aminothiophenol on 235 the ZnP<sub>2</sub> (011) surface and their adsorption energies are shown in Figure 5. Horizontal positioning of 236 the 4-aminothiophenol resulted in an interaction very close to that of a bidentate biding mode (Figure 237 5a), with a Zn-N bond of 2.31 Å and a distance between the -SH sulphur atom and the closest surface 238 zinc atom of 2.83 Å. Despite the prolonged Zn-S distance, this type of interaction is characterised by 239 240 an adsorption energy of  $E_{ads} = -1.65 \text{ eV}$ , which is more favourable by 0.57 and 0.73 eV, respectively, than the -SH (Figure 5b) and -NH<sub>2</sub> (Figure 5c) monodentate vertical binding modes. When interacting 241 only through the -SH functional group, the adsorbate binds almost perpendicularly to the surface with 242 the Zn-S bond optimised at 2.47 Å. In the -NH<sub>2</sub> binding mode (Zn-N bond of 2.17 Å), the molecule 243 is tilted much closer to the surface at an angle of 28.30°. Transfer of negative charge to the 4-244

aminothiophenol is highest in the case of monodentate interaction through the sulphur atom,  $-0.11 e^{-1}$ , and lowest for the opposite case of interacting solely through the amino group,  $-0.08 e^{-1}$ .



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Figure 5 Top (top panel) and side views (bottom panle) of horizontal (a), -SH vertical (b), and -NH<sub>2</sub> vertical (c) adsroption modes of 4-aminothiophenol on the  $ZnP_2$  (011) surface. For clarity, only the top most layers of the surface are shown. Calculated adsorption energies are listed below each structure. For colour legend refer to Figure 2.

 $ZnP_2$  (100) surface: The three binding modes of 4-aminothiophenol on the  $ZnP_2$  (100) surface, 252 together with their corresponding adsorption energies, are presented in Figure 6. Zn-S and Zn-N 253 bonds formed in the horizontal bidentate mode (Figure 6a) have lengths of 2.56 and 2.36 Å, 254 respectively, and release an adsorption energy of -1.47 eV. For the -SH monodentate binding 255 geometry (Figure 6b), the 4-aminothiophenol molecule is tilted towards the surface at an angle of 256 10.00°, forming a Zn-S bond of 2.50 Å with the thiol hydrogen pointing away from the surface. This 257 adsorption geometry is only 0.15 eV less favourable than the bidentate binding mode. In contrast, 258 when the molecule is adsorbed in a monodentate mode through the amino group with a rather shorter 259 2.17 Å Zn-N bond, it remains almost perfectly perpendicular (Figure 6c). However, this binding mode 260 is also significantly less favourable with an adsorption energy of  $E_{ads} = -0.78 \text{ eV}$ . 261

The charges gained through the adsorption process are similar for horizontal and -SH vertical 262 interaction modes, -0.11 and -0.12 e<sup>-</sup>, respectively. However, the amount of negative charge 263 transferred from the zinc atom bound to sulphur is 0.02 e<sup>-</sup> for the -SH monodentate binding mode, 264 265 which is ten times that of the bidentate interaction, where the charge gained  $(0.002 \text{ e}^{-})$  is almost negligible, and the majority of the charge transfer comes from the Zn interacting with the -NH<sub>2</sub> group, 266 0.04 e<sup>-</sup>. Correspondingly, a significant change of 0.088 e<sup>-</sup> is observed in the charge of the zinc atom 267 interacting to form an amine monodentate, leading to a net charge gain of -0.08 e<sup>-</sup> by the 4-268 aminothiophenol. 269



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Figure 6: Top (top panel) and side views (bottom panle) of horizontal (a), -SH vertical (b), and -NH<sub>2</sub> vertical
(c) adsorption modes of 4-aminothiophenol on the ZnP<sub>2</sub> (100) surface. For clarity, only the top most layers of
the surface are shown. Calculated adsorption energies are listed below each structure. For colour legend refer
to Figure 2.

**ZnP**<sub>2</sub> (101) surface: The structures and adsorption energies of the distinct adsorption modes of 4aminothiophenol on the ZnP<sub>2</sub> (101) surface are presented in Figure 7. The (101) surface has a naturally stepped geometry which allows for efficient adsorption in the bidentate binding mode (Figure 7a), as seen in its adsorption energy of  $E_{ads} = -1.91$  eV, the most favourable of the three adsorption modes. This is also reflected in the lengths of formed S-Zn and N-Zn bonds of 2.54 and 2.17 Å. Compared to the bidentate binding, the monodentate -SH (Figure 7b) and -NH<sub>2</sub> (Figure 7c) geometries released adsorption energies of -0.79 and -1.17 eV, respectively, with tilting angles of 86.90 and 70.51°, and Zn-S and Zn-N bonds converged at 2.53 and 2.17 Å, respectively. Charge gained in the most stable horizontal bidentate adsorption geometry on the (101) surface is -0.15 e<sup>-</sup> with the zinc atom binding the nitrogen contributing three times more to the charge transfer compared to the zinc atom connected to the -SH sulphur. The 4-aminothiophenol gained charge of -0.08 e<sup>-</sup> when adsorbed in both -SH and -NH<sub>2</sub> monodentate geometries.



#### 287

**Figure 7:** Top (top panel) and side views (bottom panle) of horizontal (a), -SH vertical (b), and -NH<sub>2</sub> vertical (c) adsroption modes of 4-aminothiophenol on the  $ZnP_2$  (101) surface. For clarity, only the top most layers of the surface are shown. Calculated adsorption energies are listed below each structure. For colour legend refer to Figure 2.

292  $ZnP_2$  (110) surface: Only one binding mode was successfully optimised on the ZnP<sub>2</sub> (110) surface 293 and its structure is depicted in Figure 8. The zigzag arrangement of surface zinc atoms and their 294 interatomic distance hamper the 4-aminothiophenol molecule from forming a bidentate geometry 295 with one S-Zn and one N-Zn bond. The molecule hence binds to the surface through a single S-Zn 296 bond instead, with the adsorption energy of  $E_{ads} = -1.38$  eV and a charge transfer of -0.06 e<sup>-</sup>.



-1.38 eV

Figure 8: Top (top panel) and side views (bottom panle) of horizontal adsorption mode of 4-aminothiophenol
 on the ZnP<sub>2</sub> (110) surface. For clarity, only the top most layers of the surface are shown. Calculated adsorption
 energy is also given. For colour legend refer to Figure 2.

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302 ZnP2 (111) surface: The 4-aminothiophenol binds to the (111) surface in two monodentate -SH geometries, horizontal (Figure 9a) and tilted (Figure 9b). The horizontal binding mode is 303 characterised by the stronger adsorption energy of  $E_{ads} = -1.41$  eV, compared to  $E_{ads} = -0.82$  eV for 304 the tilted mode. A true bidentate mode could not be established, even when positioning the molecule 305 parallel to the surface, due to the inconvenient arrangement of the topmost Zn atoms. In the horizontal 306 -SH geometry, the Zn-S bond has a length of 2.52 Å, while the distance between the nitrogen and the 307 nearest zinc surface atom is 3.89 Å. The Zn-S bond distance in the tilted -SH monodentate geometry 308 is predicted at 2.58 Å with a tilt angle of 32.72°. The monodentate -NH<sub>2</sub> vertical binding mode (Figure 309 9c), established through the 2.15 Å Zn-N bond, is only 0.18 eV less favourable than when 4-310 aminothiophenol is adsorbed in the horizontal -SH geometry, and it releases an adsorption energy of 311 -1.23 eV. Overall, the 4-amiothiophenol gained a charge of -0.13 e<sup>-</sup> and -0.11 e<sup>-</sup> when adsorbed in the 312 313 horizontal and tilted -SH geometries, respectively, and -0.09 e<sup>-</sup> when binding through the -NH<sub>2</sub> group.



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Figure 9 Top (top panel) and side views (bottom panle) of -SH horizontal (a), -SH vertical (b), and -NH<sub>2</sub>
vertical (c) adsorption modes of 4-aminothiophenol on the ZnP<sub>2</sub> (111) surface. For clarity, only the top most
layers of the surface are shown. Calculated adsorption energies are listed below each structure. For colour
legend refer to Figure 2.

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#### 320 **3.2** Functionalisation at full coverage of the ZnP<sub>2</sub> surfaces

321 Full coverage functionalisation of ZnP<sub>2</sub> surfaces was investigated by considering multiple 4aminothiophenol molecules adsorbed in the horizontal binding mode, which was shown to be the 322 most favourable type of interaction on all surfaces. Each surface was functionalised with a full 323 monolayer of 4-aminothiophenol, where monolayer coverage had been established when no 324 combination of uncoordinated zinc atoms remained available to accommodate another adsorbate 325 molecule in a flat bidentate binding mode. The calculated adsorption energies at full coverage are 326 reported in Error! Reference source not found., with the strength of adsorption predicted to follow 327 the trend (010) > (101) > (011) > (110) > (100) > (111) > (001). Using the full coverage energetics, 328 329 the surface energies and work functions of the functionalised surfaces were also calculated and are listed in Error! Reference source not found. 330

To determine the effect of the functionalisation on the electronic properties of  $ZnP_2$  surfaces, changes in the decomposed densities of state (DOS) and band gap energies upon adsorption have been examined. Orbital decomposed DOS of the (001) surface before and after full monolayer functionalisation are shown in Figure 10. Similar to the densities of state of the bulk material, the top of the valence band of the (001) surface is dominated by p states of phosphorus and p and d states of zinc, while the bottom of the conduction band is composed mainly of the s states of P atoms and pstates of Zn atoms.

**Table 3:** Adsorption energy per molecule for horizontal binding mode ( $\overline{E}_{ads}$ ), surface energy ( $\gamma_f$ ), percentage stabilisation, and work function ( $\phi_f$ ) for seven low Miller index surfaces of monoclinic ZnP<sub>2</sub> upon a full monolayer functionalisation with 4-aminothiophenol.

surface	$\bar{E}_{ads}$ / eV	$\gamma_{\rm f}$ / Jm <sup>-2</sup>	stabilisation / %	$\phi_{ m f}$ / eV
(001)	-1.13	0.678	-6.8	4.207
(010)	-2.10	0.881	-7.1	3.816
(011)	-1.65	0.722	-2.3	3.927
(100)	-1.44	0.853	-4.0	4.924
(101)	-1.90	0.770	-14.4	4.269
(110)	-1.51	0.898	-12.6	4.837
(111)	-1.40	0.883	-10.3	3.057

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Figure 10: Left: (001) surface of monoclinic  $ZnP_2$  functionalised with a full monolayer of 4-aminothiophenol in horizontal binding mode in top view (top pannel) and side view (bottom pannel). Right: orbital decomposed DOS of bare 001 surface of monoclinic  $ZnP_2$  with accompanying band gap energy,  $E_g$  (top pannel); orbital decomposed DOS of functionalised 001 surface of monoclinic  $ZnP_2$  presented on the left with accompanying band gap energy,  $E_g$  (middle pannel); enlarged DOS of the atoms of 4-aminothiophenol after monolayer functionalisation of the (001) surface of monoclinic  $ZnP_2$  (bottom panel).

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The adsorption of 4-aminothiophenol is shown to be characterised by the Zn-S and Zn-N bonding states localised at around -3.0 eV below the Fermi level. The electronic band gaps of the naked and functionalised (001) surfaces are calculated at 0.936 and 0.924 eV, respectively, indicating that the functionalisation with 4-aminothiophenol has only a negligible effect on the electronic structure. The composition of the valence and conduction band edges of the functionalised surface remained unchanged and no additional states were introduced in the close proximity or within the energy gap.
Corresponding figures of the orbital decomposed DOS for the remaining six surfaces can be found in
the supplementary information, Figures S3 and S4, where no significant effects of the adsorbate
monolayers on the electronic properties was observed, and band gap energies of the functionalised
surfaces remained within 0.005-0.100 eV of their naked counterparts.

#### 360 3.3 Morphology of $ZnP_2$ nanocrystal before and after 4-aminothiophenol functionalistion

Modifications in the shape of the  $ZnP_2$  nanocrystal after 4-aminothiophenol functionalisation were ascertained through the Wulff construction [56], based on the surface energies of the clean and monolayer-protected surfaces, Figure 11. Under thermodynamic conditions, the equilibrium morphology of a crystal possesses minimal total surface free energy for a given volume based on the Gibbs formulation. Functionalisation is demonstrated to have a stabilising effect on all  $ZnP_2$  surfaces, as reflected in the lower surface energies, with the extent of the stabilisation varying from 2.3% for the (011) surface up to 14.4% for the (101) surface.



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Figure 11: Wulff morphology of bare (left) and 4-aminothiophenol functionalised (rigth) monoclinic ZnP<sub>2</sub>
 crystal.

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Adsorption induced changes in the surface energies are also visible in the final morphology of the ZnP<sub>2</sub> nanoparticle. Prior to the functionalisation, the equilibrium shape of the bare crystal contains six out of the seven surfaces studied, with the (111) surface not appearing in the morphology. The (001) and (011) surfaces account for the greatest share of the surface area, in agreement with their favourable surface stabilities among the seven surfaces investigated. Differences in the adsorption strength of 4-aminothiophenol on the seven surfaces influences their stabilities and, hence, their expression in the morphology of the functionalised nanoparticle. The weaker adsorption on the (001) and (100) surfaces compared to the others resulted in a reduction of their surface shares, whereas the (101) and (110) surfaces experience an increase in their share of the available surface area, resulting from the higher stabilisation from the 4-aminothiophenol adsorption. Owing to the stabilisation of the surface after functionalisation, it now appears in the final equilibrium morphology.

# 383 3.4 Thermodynamic stability of functionalised ZnP<sub>2</sub> surfaces

Calculated adsorption energies are good descriptors of the strength of interaction between the 4aminothiophenol and various ZnP<sub>2</sub> surfaces, but they do not give any indication of the effects of experimental conditions and chemical potential of the adsorbate on the stability of functionalised surfaces. Stabilities of the surfaces upon functionalisation were therefore estimated and compared based on the change in the free Gibbs surface energy with respect to the conditions of temperature and pressure ( $\Delta \gamma_{t}(T, p)$ ) as:

390 
$$\Delta \gamma_{\rm f}(T,p) = \frac{E_{\rm funct surface}^{\rm DFT} - E_{\rm surface}^{\rm DFT}}{2\rm A} - \frac{m}{2\rm A} \Delta \mu_{\rm a}(T,p)$$

where  $\Delta \mu_{a}(T, p)$  is the variation of the chemical potential of 4-aminothiophenol to account for experimental conditions. Assuming adsorbate-rich conditions (corresponding to  $\Delta \mu_{a}(T, p) = 0$ , when the chemical potential of 4-aminothiophenol equals the total energy of the molecule in the gas phase), calculated changes in the free Gibbs surface energies are represented in Figure 12a. All surfaces undergo full monolayer functionalisation under these conditions, with the most significant change in the Gibbs surface free energy noted for the (101) and (110) surfaces.

397 To fully capture the behaviour of the surfaces under various conditions of adsorbate concentrations, 398 surface phase diagrams have been suggested based on the changes in the free Gibbs surface energies 399 with chemical potential of the 4-aminothiophenol. The phase diagrams were plotted for the two most stable functionalised surfaces, (101) and (110), as shown in Figure 12b and c, respectively. The two surfaces show similar trends, with monolayer coverage favoured up to the chemical potential of -1.50 and -2.00 eV. A transition to the lower coverage of 0.50 ML occurs at  $\Delta \mu_a = -1.89$  eV for the (101) surface, while the appearance of the bare surface should occur shortly after, at  $\Delta \mu_a = -1.91$  eV, which is shown in the enlarged area of the plot.



405

**406 Figure 12**: (a) Surface free-energy variations for seven low Miller index surfaces of monoclinic  $ZnP_2$ 407 functionalised with a single molecule of 4-aminothiophenol and a full monolayer under adsorbate-rich 408 conditions ( $\mu_a = 0.00 \text{ eV}$ ). Surface phase diagrams of the (101) surface (b) with the enlarged area of the 409 intersection, and of the (110) surface (c). y-axis is the same for the two surface phase diagrams.

410

Conversely, an immediate transition to a bare surface is observed at  $\Delta \mu_a = -1.51$  eV for the (110) 411 surface without the appearance of the surface with half a monolayer of 4-aminothiophenol. The 412 crossovers between high and low coverages (or, in most cases, bare surfaces) of all seven surfaces 413 occur in the range of -1.50 to -2.00 eV; the only exception is the (001) surface where the intersection 414 happens at  $\Delta \mu_a = -1.12$  eV. If standard conditions are considered (p = 1 atm, T = 300 K), those 415 transitions can be assigned to environments with extremely low adsorbate concentrations, 416  $p \sim 10^{-15} - 10^{-17}$  atm for the six surfaces or  $p \sim 10^{-10}$  atm for the (001) surface (note: ultra-high 417 vacuum chambers operate at about  $10^{-12}$  atm). 418

The effect of humidity was introduced by adding the variation of the surface energies with adsorbed water. Previous study has shown spontaneous interaction of water molecules with all  $ZnP_2$  surfaces and the calculated surface energies after full water monolayer adsorption under p = 1 atm

 $(p_{\rm H_2O}=0.035 \text{ atm})$  and T = 300 K have also been provided in the phase diagrams (red dashed lines). 422 It has to be noted that only the lowest chemical potential of water needed for the formation of the full 423 monolayer was considered and the true surface energy could hence be even lower. When the transition 424 from 1.00 ML of 4-aminothiopnehol to 1.00 ML of water will take place depends on the surface, but 425 it always occurs at much higher chemical potentials of 4-aminothiophenol compared to the transitions 426 towards the non-functionalised surfaces. For the surfaces whose phase diagrams are depicted in 427 Figure 12, transitions are observed at  $\Delta \mu_a = -0.82$  eV for the (101) surface and  $\Delta \mu_a = -1.08$  eV for 428 the (110) surface, which corresponds to the partial pressures of  $p \sim 10^{-6} - 10^{-9}$  atm. Further 429 estimation of the stability of the functionalised surfaces under more realistic aqueous media is not 430 plausible solely from DFT calculations, but the provided results are suggestive of the possible 431 protection of ZnP<sub>2</sub> nanoparticles under humid conditions by 4-aminothiophenol functionalisation. 432

## 433 4 CONCLUSIONS

Density functional theory calculations have been carried out to provide detailed atomic-level insights 434 435 into the effects of the functionalisation by 4-aminothiophenol on the structural and electronic properties of monoclinic ZnP<sub>2</sub> nanoparticles. The strongest interaction between the 4-436 aminothiophenol and all the ZnP<sub>2</sub> surfaces was established when the molecule was located close to 437 438 the surface in a horizontal position. When the arrangement of the topmost zinc atoms was favourable, this provided an adsorption site which allowed both the -NH<sub>2</sub> and -SH functional groups to form 439 covalent bonds with the surface. Analysis of electronic structures of the surfaces functionalised by a 440 441 full monolayer revealed minimal changes in the band gap energies, without new states in the band gap region, although changes in the morphology of the nanocrystals were much more prominent. 442 Thermodynamically, the surfaces were found to be significantly stabilised after functionalisation, 443 with full monolayer coverages favoured under adsorbate-rich conditions and expected to persist even 444 in the presence of water, although it remains to see if in aqueous media this improvement in the 445 446 stability remains sufficient to overcome the formation of a water monolayer. However, minimal

447	modifications of the optically favourable band gap energies and adsorption strengths comparable to
448	those observed at $Zn_3P_2$ surfaces indicate that 4-aminothiophenol is a promising candidate for the
449	functionalisation of monoclinic ZnP <sub>2</sub> nanoparticles and thin films for photovoltaic applications.
450	ASSOCIATED CONTENT
451	*S Supporting Information
452	The Supporting Information contains adsorption structures, Bader charge analyses, and the orbital
453	decomposed DOS of the monoclinic $ZnP_2$ surfaces with and without a full monolayer
454	functionalisation with 4-aminothiophenol.
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